NSN 5961-01-251-1021

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Diode Semiconductor Device - Page 1 of 1



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Terminal Length:
Between 1.000 inches and 1.300 inches
Overall Diameter:
Between 0.085 inches and 0.140 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
27.0 breakdown voltage, dc
Current Rating Per Characteristic:
40.00 milliamperes collector current, dc horsepower metric
Power Rating Per Characteristic:
1500.0 watts small-signal input power, common-emitter nanoamperes
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/516 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: